



DMT6009LPS

PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Tc = +25°С
60V	10mΩ @ V _{GS} = 10V	87A
000	12mΩ @ V _{GS} = 4.5V	79A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- High frequency switching
- Sync. rectification
- DC-DC converters

Features

 100% Unclamped Inductive Switching – Ensures More Reliable and Robust End Application

60V N-CHANNEL ENHANCEMENT MODE MOSFET

- Low RDS(ON) Minimizes Power Losses
- Low Q_g Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

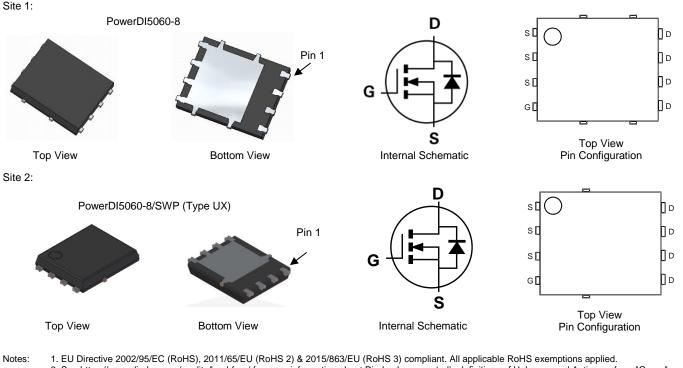
https://www.diodes.com/products/automotive/automotiveproducts/.

• This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (©3)
- Weight: 0.097 grams (Approximate)



2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

1 of 9 www.diodes.com

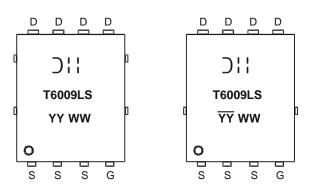


Ordering Information (Note 4)

Part Number	Paakaaa	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMT6009LPS-13	PowerDI5060-8	2,500	Tape & Reel	
DIVITO009LPS-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



);; = Manufacturer's Marking T6009LS = Product Type Marking Code YYWW $\underline{=}$ Date Code Marking YY or YY = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage		Vdss	60	V
Gate-Source Voltage		V _{GSS}	±16	V
Continuous Drain Current (Note E)	T _A = +25°C	- ID	10.6	A
Continuous Drain Current (Note 5)	T _A = +70°C		9.1	
Continuous Drain Current (Note 6)	Tc = +25°C	- I _D	87	A
Continuous Drain Current (Note 6)	$T_{\rm C} = +70^{\circ}{\rm C}$		69	
Maximum Continuous Body Diode Forward Current (Note 6)	ls	100	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	160	A
Avalanche Current, L = 0.1mH		I _{AS}	20.3	A
Avalanche Energy, L = 0.1mH		E _{AS}	20.6	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	53	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	113	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).



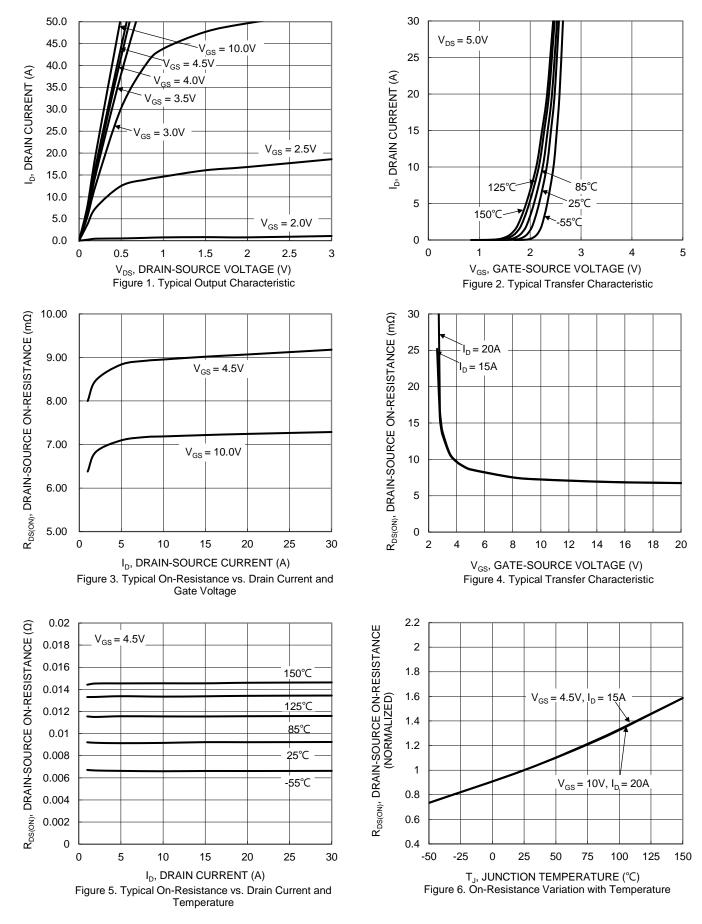
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	1 -						
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		—	1	μA	V _{DS} = 48V, V _{GS} = 0V	
Gate-Source Leakage	lgss	-	—	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	0.7	_	2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Desser	_	7.2	10	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		8.9	12	11122	$V_{GS} = 4.5 V, I_D = 15 A$	
Diode Forward Voltage	Vsd		0.9	_	V	V _{GS} = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		1,925		pF	$V_{DS} = 30V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	438	_			
Reverse Transfer Capacitance	Crss	_	41	_			
Gate Resistance	Rg	_	1.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	-	33.5	_			
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	15.6	_	nC	V _{DS} = 30V, I _D = 13.5A	
Gate-Source Charge	Qgs	_	4.7	_	nc		
Gate-Drain Charge	Q _{gd}	_	5.3	_			
Turn-On Delay Time	td(ON)	-	4.5			$V_{DD} = 30V, V_{GS} = 10V$ R _G = 6Ω, I _D = 13.5A	
Turn-On Rise Time	tR	_	8.6		I		
Turn-Off Delay Time	tD(OFF)	_	35.9		ns		
Turn-Off Fall Time	tF		15.7		1		
Body Diode Reverse Recovery Time	trr		18.2		ns		
Body Diode Reverse Recovery Charge	Qrr		33.1	—	nC	I _F = 13.5A, dl/dt = 400A/µs	

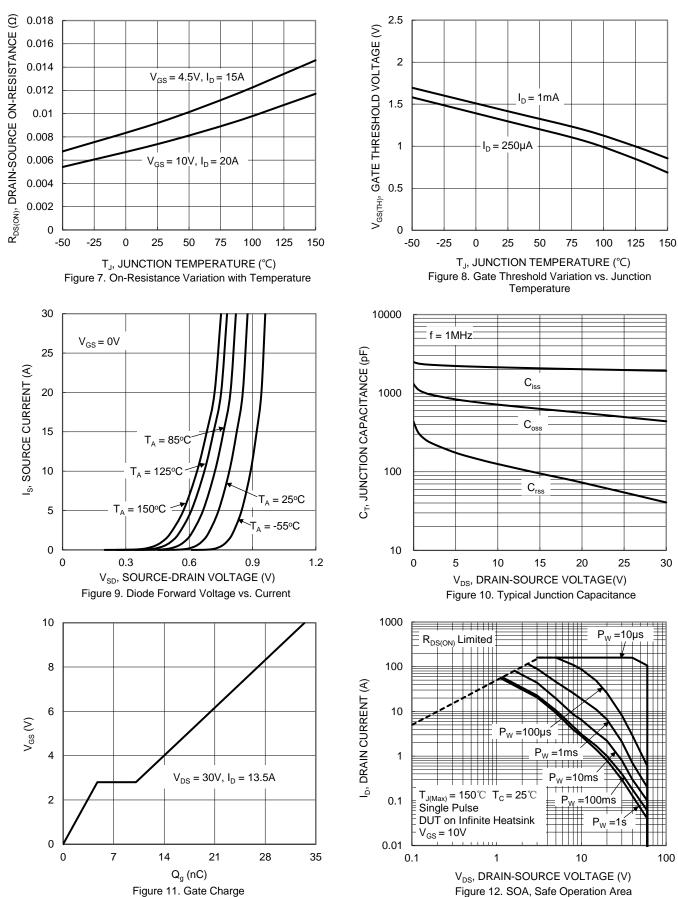
Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.



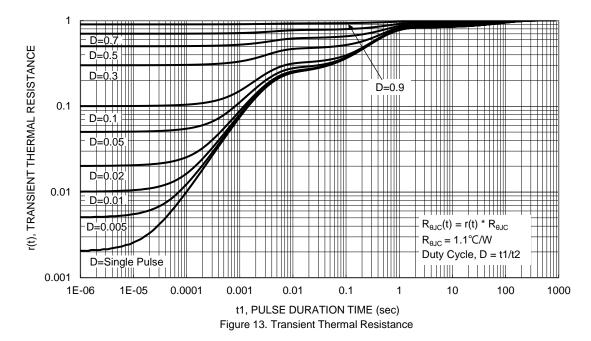
DMT6009LPS













Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

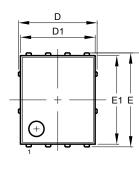
E3 E2

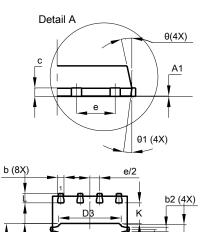
G

Detail A

Site 1:

PowerDI5060-8

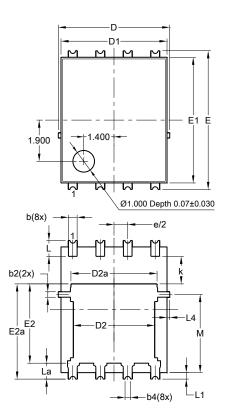




D2

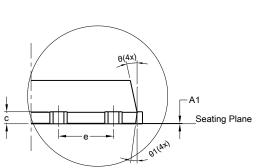
	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
C	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
Μ	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All	All Dimensions in mm				

Site 2:

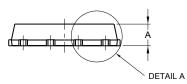


PowerDI5060-8/SWP (Type UX)

b3 (4X)



DETAIL A



		PowerDI5060-8/SWP			
(Type UX)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	0).25REF			
С	0.230		0.277		
D	5	.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
ш	6	.40 BS0	0		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0	.050RE	F		
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

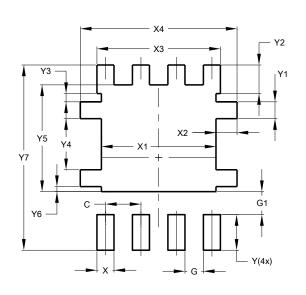
DMT6009LPS Document number: DS38369 Rev. 3 - 2



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

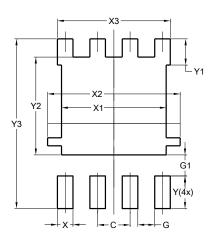


Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
¥7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	5.190
X3	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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